NSN 5961-01-085-4001

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View Online at https://aerobasegroup.com/nsn/5961-01-085-4001 **Inclosure Material:** Metal **Overall Length:** Between 1.103 inches and 1.107 inches **Overall Height:** 0.700 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 7.00 milliamperes source cutoff current and 250.00 microamperes zero-gate-voltage source current preset **Power Rating Per Characteristic:** 90.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 20.0 static forward current transfer ratio, common-emitter and 100.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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